NSN 5961-01-480-1819

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-480-1819 **Inclosure Material:** Glass **Overall Length:** 2.175 inches **Overall Diameter:** 0.080 inches **End Application:** Electronic component assembly **Electrode Internally-electrically Connected To Case:** Cathode **Criticality Code Justification: Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 12.0 regulator voltage **Voltage Tolerance In Percent:** -2.0/+2.0 **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Zener diode, multi mounting positions; hermatically sealed glass casing; mettalurical bonding Shelf Life: N/a **Unit Of Measure:** Demilitarization: No